## **HD74HC32**

Quad. 2-input OR Gates

# **HITACHI**

### **Features**

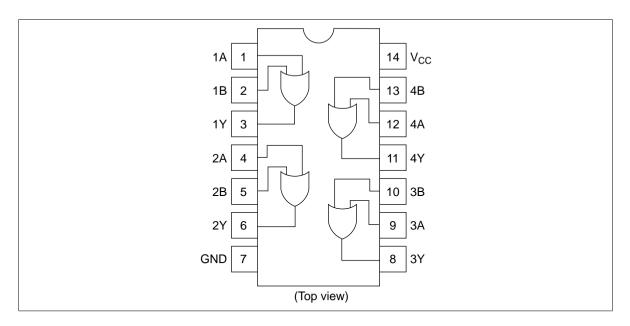
High Speed Operation: t<sub>pd</sub> = 10 ns typ (C<sub>L</sub> = 50 pF)
 High Output Current: Fanout of 10 LSTTL Loads

• Wide Operating Voltage:  $V_{CC} = 2$  to 6 V

• Low Input Current: 1 µA max

• Low Quiescent Supply Current:  $I_{CC}$  (static) = 1  $\mu$ A max (Ta = 25°C)

### **Pin Arrangement**





## **HD74HC32**

## **DC** Characteristics

			Ta =	: 25°(	;	Ta = - +85°C	-40 to	_		
Item	Symbol	V <sub>cc</sub> (V)	Min	Тур	Max	Min	Max	Unit	Test Condition	าร
Input voltage	$V_{IH}$	2.0	1.5	_	_	1.5	_	V		
		4.5	3.15	_	_	3.15	_	_		
		6.0	4.2	_	_	4.2	_	=		
	V <sub>IL</sub>	2.0	_	_	0.5	_	0.5	V		
		4.5	_	_	1.35	_	1.35	=		
		6.0	_	_	1.8	_	1.8	=		
Output voltage	V <sub>OH</sub>	2.0	1.9	2.0	_	1.9	_	V	$Vin = V_{IH} \text{ or } V_{IL}$	$I_{OH} = -20  \mu A$
		4.5	4.4	4.5	_	4.4	_	_		
		6.0	5.9	6.0	_	5.9	_	=		
		4.5	4.18	_	_	4.13	_	_		$I_{OH} = -4 \text{ mA}$
		6.0	5.68	_	_	5.63	_	=		$I_{OH} = -5.2 \text{ mA}$
	V <sub>OL</sub>	2.0	_	0.0	0.1	_	0.1	V	$Vin = V_{IH} \text{ or } V_{IL}$	I <sub>OL</sub> = 20 μA
		4.5	_	0.0	0.1	_	0.1	_		
		6.0	_	0.0	0.1	_	0.1	=		
		4.5	_	_	0.26	_	0.33	=		I <sub>OL</sub> = 4 mA
		6.0	_	_	0.26	_	0.33	=		I <sub>OL</sub> = 5.2 mA
Input current	lin	6.0	_	_	±0.1	_	±1.0	μΑ	Vin = V <sub>CC</sub> or GN	ND
Quiescent supply current	I <sub>cc</sub>	6.0	_	_	1.0	_	10	μΑ	Vin = V <sub>cc</sub> or GN	ND, lout = $0 \mu A$

**AC Characteristics** ( $C_L = 50 \text{ pF}$ , Input  $t_r = t_f = 6 \text{ ns}$ )

	Ta = -40 to
Ta = 25°C	+85°C

				_				-	
Item	Symbol	V <sub>cc</sub> (V)	Min	Тур	Max	Min	Max	Unit	Test Conditions
Propagation delay	t <sub>PLH</sub>	2.0	_	_	100	_	125	ns	
time		4.5	_	10	20	_	25		
		6.0	_	_	17	_	21	_	
	t <sub>PHL</sub>	2.0	_	_	100	_	125	ns	
		4.5	_	10	20	_	25	_	
		6.0	_	_	17	_	21	_	
Output rise time	t <sub>TLH</sub>	2.0	_	_	75	_	95	ns	
		4.5	_	5	15	_	19	_	
		6.0	_	_	13	_	16	_	
Output fall time	t <sub>THL</sub>	2.0	_	_	75	_	95	ns	
		4.5	_	5	15	_	19	_	
		6.0	_	_	13	_	16	=	
Input capacitance	Cin	_	_	5	10	_	10	pF	



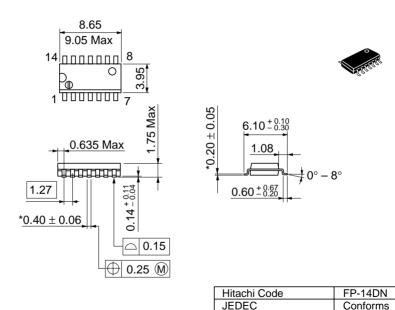
Hitachi Code	DP-14
JEDEC	Conforms
EIAJ	Conforms
Weight (reference value)	0.97 g



Weight (reference value)

0.23 g

\*Dimension including the plating thickness
Base material dimension



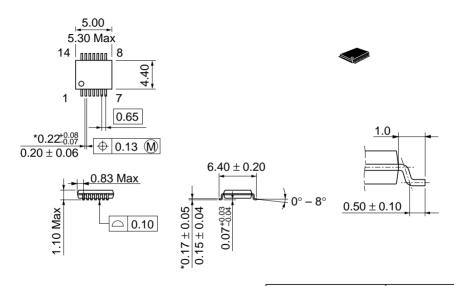
EIAJ

Weight (reference value)

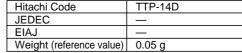
Conforms

0.13 g

\*Pd plating



\*Dimension including the plating thickness
Base material dimension



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## HTACHI

#### Hitachi, Ltd.

Semiconductor & Integrated Circuits.

Nippon Bldg., 2-6-2, Ohte-machi, Chiyoda-ku, Tokyo 100-0004, Japan Tel: Tokyo (03) 3270-2111 Fax: (03) 3270-5109

NorthAmerica URL Europe

http://www.hitachi-eu.com/hel/ecg http://www.has.hitachi.com.sg/grp3/sicd/index.htm http://www.hitachi.com.tw/E/Product/SICD\_Frame.htm Asia (Singapore) Asia (Taiwan) Asia (HongKong) http://www.hitachi.com.hk/eng/bo/grp3/index.htm

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#### For further information write to:

Hitachi Semiconductor (America) Inc. 179 East Tasman Drive, San Jose,CA 95134 Tel: <1> (408) 433-1990 Fax: <1>(408) 433-0223 Hitachi Europe GmbH Electronic components Group Dornacher Stra§e 3 D-85622 Feldkirchen, Munich Germany Tel: <49> (89) 9 9180-0

Fax: <49> (89) 9 29 30 00 Hitachi Europe Ltd. Electronic Components Group. Whitebrook Park Lower Cookham Road

Maidenhead Berkshire SL6 8YA, United Kingdom

Tel: <44> (1628) 585000 Fax: <44> (1628) 778322 Hitachi Asia Pte. Ltd. 16 Collyer Quay #20-00 Hitachi Tower Singapore 049318 Tel: 535-2100 Fax: 535-1533

Hitachi Asia Ltd. Taipei Branch Office 3F, Hung Kuo Building. No.167, Tun-Hwa North Road, Taipei (105) Tel: <886> (2) 2718-3666

Fax: <886> (2) 2718-8180

Hitachi Asia (Hong Kong) Ltd. Group III (Electronic Components) 7/F., North Tower, World Finance Centre, Harbour City, Canton Road, Tsim Sha Tsui, Kowloon, Hong Kong Tel: <852> (2) 735 9218

Fax: <852> (2) 730 0281 Telex: 40815 HITEC HX

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